imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



Product data sheet

1. General description

The 74HC4049 is a hex inverter with over-voltage tolerant inputs. Inputs are overvoltage tolerant to 15 V. This enables the device to be used in HIGH-to-LOW level shifting applications.

2. Features and benefits

- Low-power dissipation
- Complies with JEDEC standard no. 7A
- ESD protection:
 - ◆ HBM JESD22-A114F exceeds 2 000 V
 - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

3. Ordering information

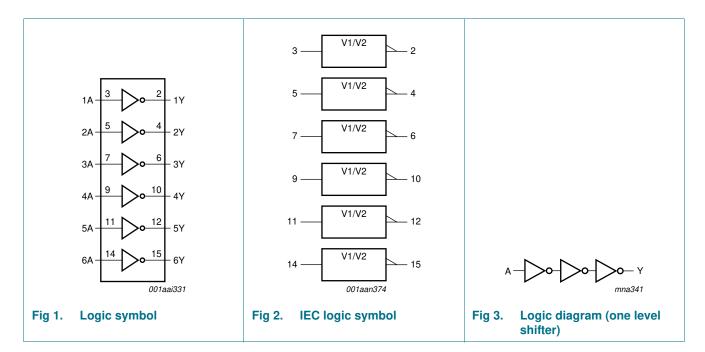
Table 1.Ordering information

Type number	Package									
	Temperature range	Name	Description	Version						
74HC4049N	–40 °C to +125 °C	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4						
74HC4049D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1						
74HC4049DB	–40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1						
74HC4049PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1						



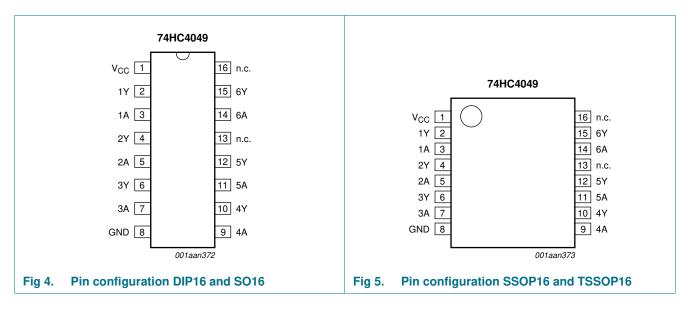
Hex inverting HIGH-to-LOW level shifter

4. Functional diagram



5. Pinning information

5.1 Pinning



Hex inverting HIGH-to-LOW level shifter

5.2 Pin description

Table 2.	Pin description	
Symbol	Pin	Description
V _{CC}	1	supply voltage
1Y to 6Y	2, 4, 6, 10, 12, 15	output
1A to 6A	3, 5, 7, 9, 11, 14	input
GND	8	ground (0 V)
n.c.	13, 16	not connected

6. Functional description

Table 3. Function table [1]	
Input	Output
nA	nY
L	н
Н	L

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

7. Limiting values

Table 4.Limiting values

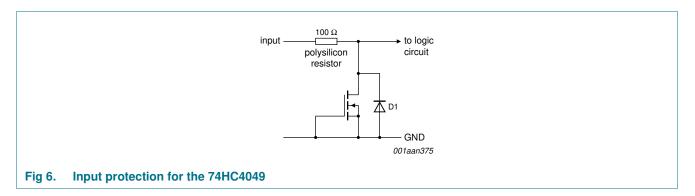
In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

					,
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7	V
V _{IK}	input clamping voltage		-0.5	+16	V
I _{IK}	input clamping current	$V_{I} < -0.5 V$	-20	-	mA
I _{OK}	output clamping current	$V_O < -0.5$ V or $V_O > V_{CC}$ + 0.5 V	-	±20	mA
lo	output current	$V_{O} = -0.5$ V to (V _{CC} + 0.5 V)	-	±25	mA
I _{CC}	supply current		-	+50	mA
I _{GND}	ground current		-	-50	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	DIP16 package	<u>[1]</u> -	750	mW
		SO16, SSOP16 and TSSOP16 packages	[2] _	500	mW

[1] For DIP16 package: P_{tot} derates linearly with 12 mW/K above 70 °C.

For SO16 package: P_{tot} derates linearly with 8 mW/K above 70 °C.
 For SSOP16 and TSSOP16 packages: P_{tot} derates linearly with 5.5 mW/K above 60 °C.

Hex inverting HIGH-to-LOW level shifter



8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		2.0	5.0	6.0	V
VI	input voltage		0	-	15	V
Vo	output voltage		0	-	V_{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 2.0 \text{ V}; \text{ V}_{I} = 2.0 \text{ V}$	-	-	625	ns/V
		$V_{CC} = 4.5 \text{ V}; \text{ V}_{I} = 4.5 \text{ V}$	-	1.67	139	ns/V
		$V_{CC} = 6.0 \text{ V}; \text{ V}_{I} = 6.0 \text{ V}$	-	-	83	ns/V
		$V_{CC} = 6.0 \text{ V}; \text{ V}_{I} = 10.0 \text{ V}$	-	-	81	ns/V
		$V_{CC} = 6.0 \text{ V}; \text{ V}_{I} = 15.0 \text{ V}$	-	-	83	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol Parameter		Conditions	itions T _{amb} = 25 °C		T _{amb} = −40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit	
			Min	Тур	Max	Min	Max	Min	Max	
V _{IH}	HIGH-level	$V_{CC} = 2.0 V$	1.5	1.3	-	1.5	-	1.5	-	V
	input voltage	$V_{CC} = 4.5 V$	3.15	2.4	-	3.15	-	3.15	-	V
		$V_{CC} = 6.0 V$	4.2	3.1	-	4.2	-	4.2	-	V
V _{IL} LOW-level	$V_{CC} = 2.0 V$	-	0.7	0.5	-	0.5	-	0.5	V	
	input voltage	$V_{CC} = 4.5 V$	-	1.8	1.35	-	1.35	-	1.35	V
		$V_{CC} = 6.0 V$	-	2.3	1.8	-	1.8	-	1.8	V
V _{OH}	HIGH-level	$V_I = V_{IH} \text{ or } V_{IL}$								
	output voltage	I_O = $-20~\mu\text{A};~V_{CC}$ = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		$I_O = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	-	-	3.84	-	3.7	-	V
		I_{O} = –5.2 mA; V_{CC} = 6.0 V	5.48	-	-	5.34	-	5.2	-	V
74HC4049		All information provided in	this docume	ent is subject	to legal discla	aimers.		© NX	P B.V. 2013. All ri	ghts reserved

Hex inverting HIGH-to-LOW level shifter

Symbol Parameter Conditions T_{amb} = 25 °C T_{amb} = -40 °C to T_{amb} = -40 °C to Unit +85 °C +125 °C Min Тур Max Min Max Min Max $V_{I} = V_{IH} \text{ or } V_{IL}$ V_{OL} LOW-level output voltage $I_{O} = 20 \ \mu A; V_{CC} = 2.0 \ V$ ۷ 0.1 0.1 0.1 _ _ _ _ $I_0 = 20 \ \mu A; V_{CC} = 4.5 \ V$ 0.1 0.1 0.1 ٧ ---- $I_{O} = 20 \ \mu A; V_{CC} = 6.0 \ V$ V _ _ 0.1 _ 0.1 0.1 _ $I_{O} = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$ 0.26 0.33 0.4 ٧ _ -_ _ $I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$ 0.26 0.33 0.4 ٧ ---- $V_I = V_{CC}$ or GND; I_I input leakage ±0.1 ±1.0 μA _ _ _ ± 1.0 - $V_{CC} = 6.0 V$ current $V_{I} = 15 \text{ V}; V_{CC} = 2.0 \text{ V} \text{ to}$ ±0.5 ±5.0 ±5.0 _ -_ _ μA 6.0 V $V_{I} = 15 \text{ V or GND}; I_{O} = 0 \text{ A};$ I_{CC} supply current 2.0 20 40 μA -_ _ _ $V_{CC} = 6.0 V$ Cı input 3.5 pF --_ -_ capacitance

Table 6. Static characteristics ... continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; for test circuit see <u>Figure 8</u>.

Symbol Parameter		Conditions		T _{amb} = 25 °C		T _{amb} = −40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit	
				Min	Тур	Max	Min	Max	Min	Max	
t _{pd}	propagation	nA to nY; see Figure 7	<u>[1]</u>								
	delay	$V_{CC} = 2.0 V$		-	28	85	-	105	-	130	ns
		$V_{CC} = 4.5 V$		-	10	17	-	21	-	26	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	8	-	-	-	-	-	ns
		$V_{CC} = 6.0 V$		-	8	14	-	18	-	22	ns
tt	transition	Yn; see Figure 7	[2]								
	time	$V_{CC} = 2.0 V$		-	19	75	-	95	-	110	ns
		$V_{CC} = 4.5 V$		-	7	15	-	19	-	22	ns
		$V_{CC} = 6.0 V$		-	6	13	-	16	-	19	ns

Hex inverting HIGH-to-LOW level shifter

Voltages	are referenced	d to GND (ground = 0 V); $C_L = 50$) pF unl	ess oth	erwise	specified	l; for test ci	rcuit see	Figure 8.	
Symbol	Parameter	Conditions	T _{ar}	_{nb} = 25	°C		= –40 °C 85 °C		= –40 °C 125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Мах	
C _{PD}	power dissipation capacitance	$C_L = 50 \text{ pF}; \text{ f} = 1 \text{ MHz};$ $V_I = \text{GND to } V_{\text{CC}}$ (3)	-	14	-	-	-	-	-	pF

Table 7. Dynamic characteristics ... continued

[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

[2] t_t is the same as t_{THL} and t_{TLH} .

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_{D} = C_{PD} \times V_{CC}{}^{2} \times f_{i} \times N + \sum (C_{L} \times V_{CC}{}^{2} \times f_{o})$ where:

 f_i = input frequency in MHz;

fo = output frequency in MHz;

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$

11. Waveforms

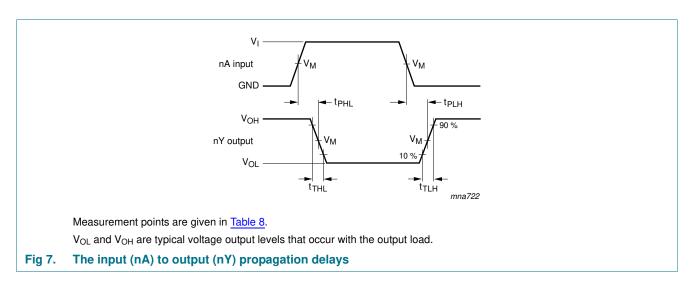


Table 8. **Measurement points**

Туре	Input	Output
	V _M	V _M
74HC4049	0.5V _{CC}	0.5V _{CC}

NXP Semiconductors

74HC4049

Hex inverting HIGH-to-LOW level shifter

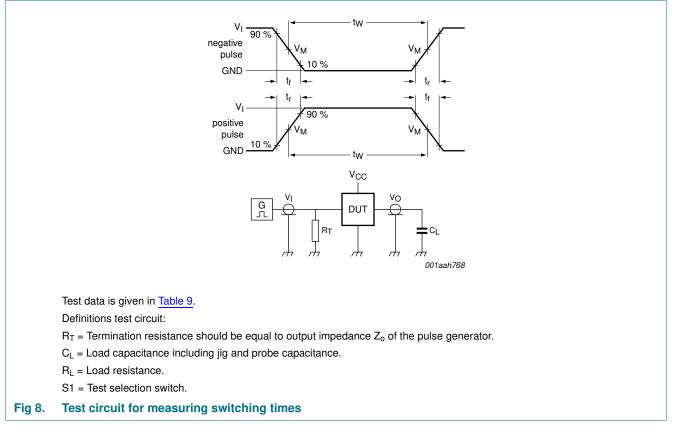


Table 9. Test data

Туре	Input		Load	Test
	VI	t _r , t _f	CL	
74HC4049	V _{CC}	6.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}

7 of 15

Hex inverting HIGH-to-LOW level shifter

12. Package outline

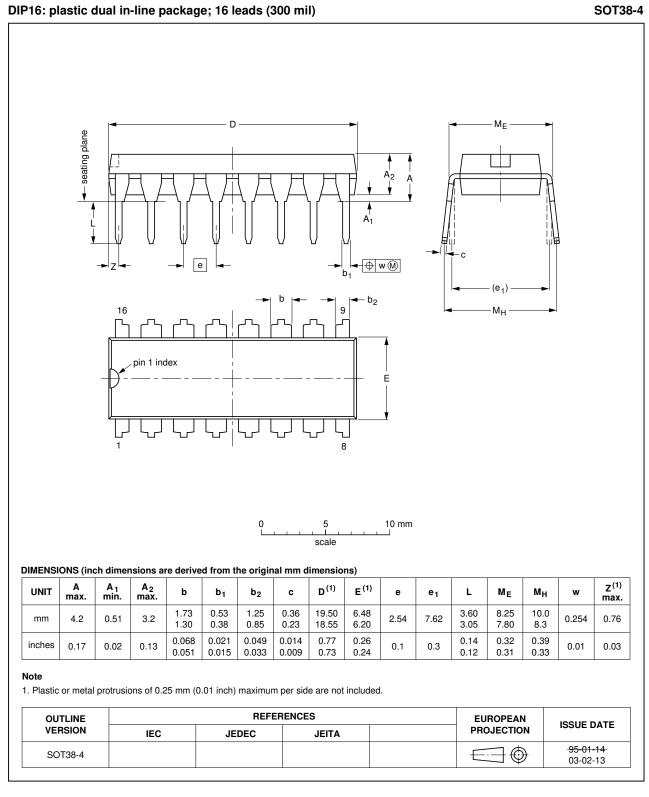


Fig 9. Package outline SOT38-4 (DIP16)

All information provided in this document is subject to legal disclaimers.

Hex inverting HIGH-to-LOW level shifter

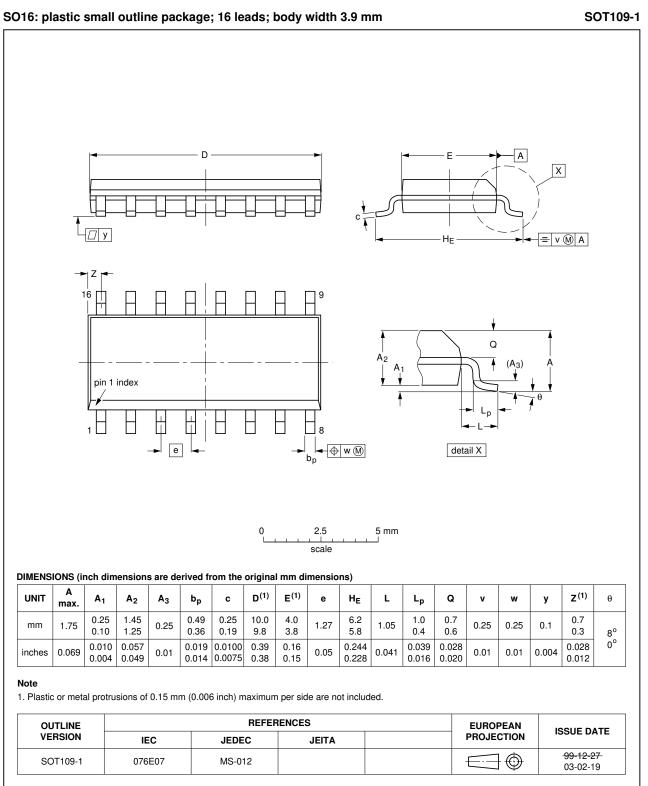


Fig 10. Package outline SOT109-1 (SO16)

Hex inverting HIGH-to-LOW level shifter

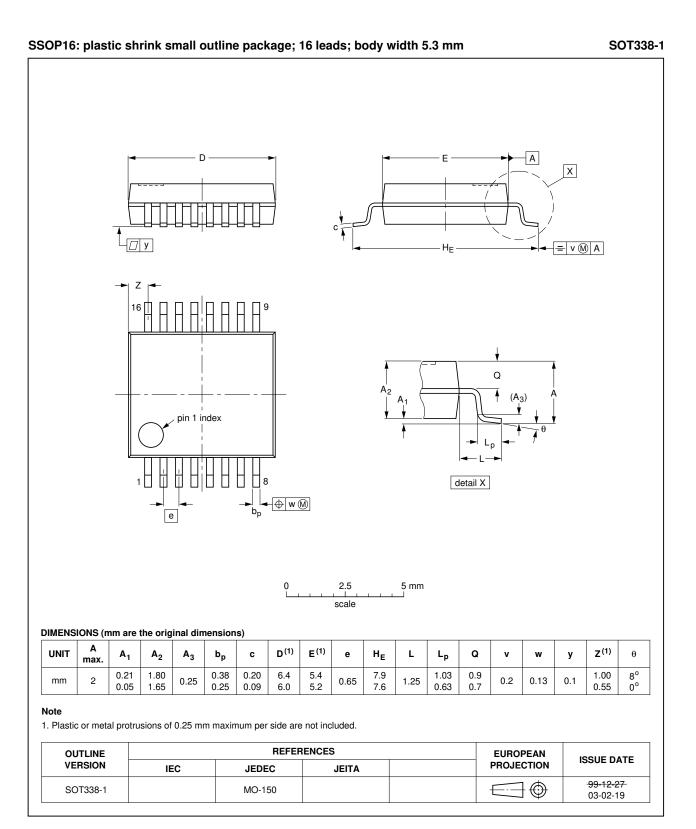


Fig 11. Package outline SOT338-1 (SSOP16)

All information provided in this document is subject to legal disclaimers.

Hex inverting HIGH-to-LOW level shifter

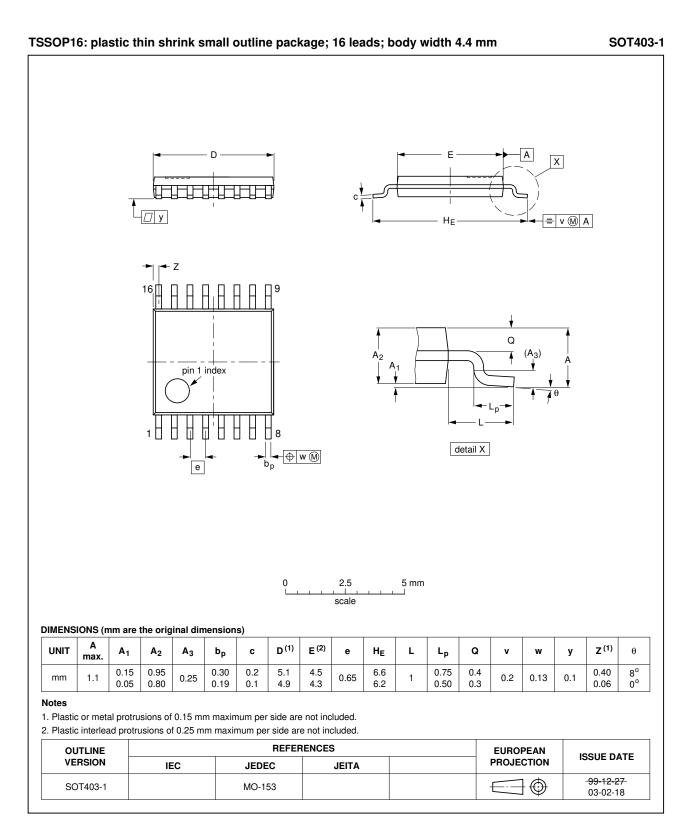


Fig 12. Package outline SOT403-1 (TSSOP16)

All information provided in this document is subject to legal disclaimers.

Hex inverting HIGH-to-LOW level shifter

13. Abbreviations

Table 10.	Abbreviations
Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC4049 v.6	20130108	Product data sheet	-	74HC4049 v.5
Modifications:	 New gener 	al description.		
74HC4049 v.5	20120803	Product data sheet	-	74HC4049 v.4
Modifications:	 Measurem 	ent points added to figure	7 (errata).	
74HC4049 v.4	20111212	Product data sheet	-	74HC4049 v.3
74HC4049 v.3	20101230	Product data sheet	-	74HC4049_CNV v.2
74HC4049_CNV v.2	19970827	Product specification	-	-

Hex inverting HIGH-to-LOW level shifter

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

15.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

15.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. NXP Semiconductors takes no responsibility for the content in this document if provided by an information source outside of NXP Semiconductors.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors and its suppliers accept no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

© NXP B.V. 2013. All rights reserved.

Hex inverting HIGH-to-LOW level shifter

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific NXP Semiconductors product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. NXP Semiconductors accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without NXP Semiconductors' warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond

NXP Semiconductors' specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies NXP Semiconductors for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond NXP Semiconductors' standard warranty and NXP Semiconductors' product specifications.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

15.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

16. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

Hex inverting HIGH-to-LOW level shifter

17. Contents

1	General description 1
2	Features and benefits 1
3	Ordering information 1
4	Functional diagram 2
5	Pinning information 2
5.1	Pinning 2
5.2	Pin description 3
6	Functional description 3
7	Limiting values 3
8	Recommended operating conditions 4
9	Static characteristics 4
10	Dynamic characteristics 5
11	Waveforms 6
12	Package outline 8
13	Abbreviations 12
14	Revision history 12
15	Legal information 13
15.1	Data sheet status 13
15.2	Definitions 13
15.3	Disclaimers
15.4	Trademarks 14
16	Contact information 14
17	Contents 15

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© NXP B.V. 2013.

All rights reserved.

For more information, please visit: http://www.nxp.com For sales office addresses, please send an email to: salesaddresses@nxp.com

Date of release: 8 January 2013 Document identifier: 74HC4049